

Transistors with Built-in Resistor **DRA9114Y0L**

DRA9114Y0L Silicon PNP epitaxial planar type

For digital circuits Complementary to DRC9114Y DRA5114Y in SSMini3 type package

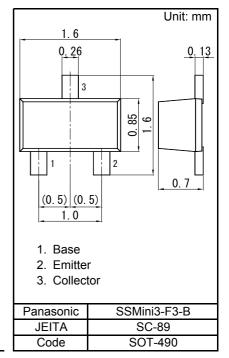
Features

- Low collector-emitter saturation voltage Vce(sat) ٠
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: LC

Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

Our marks and



Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	VCBO	-50	V	
Collector-emitter voltage (Base open)	VCEO	-50	V	Internal Co
Collector current	IC	-100	mA	
Total power dissipation	PT	125	mW	R ₁
Junction temperature	Tj	150	°C	B⊶□+↓
Operating ambient temperature	Topr	-40 to +85	°C	R ₂
Storage temperature	Tstg	-55 to +150	°C	

onnection -0 C оE Resistance R1 10 kΩ value R2 47 kΩ

Electrical Characteristics Ta = 25 °C + 3 °C

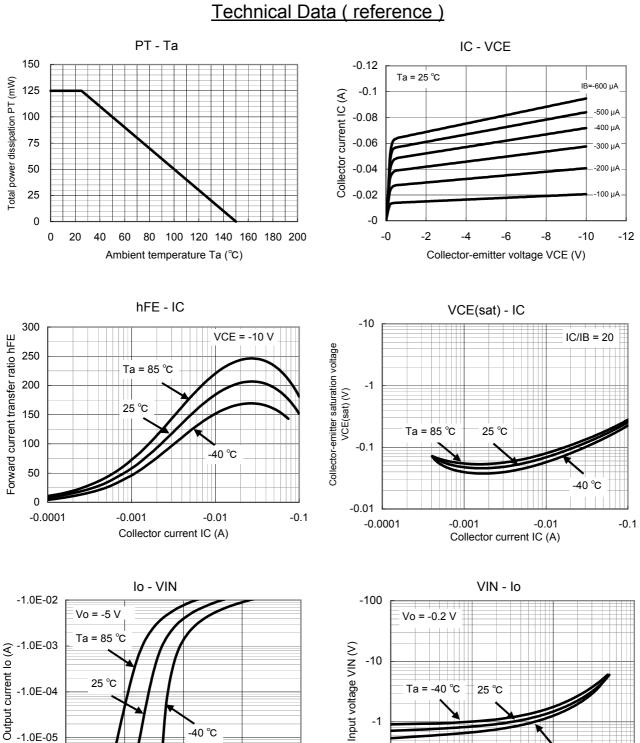
Absolute Maximum Ratings Ta = 25 °C

		A 1141				
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	VCBO	IC = -10 μA, IE = 0	-50			V
Collector-emitter voltage (Base open)	VCEO	IC = -2 mA, IB = 0	-50			V
Collector-base cutoff current (Emitter open)	ICBO	VCB = -50 V, IE = 0			-0.1	μA
Collector-emitter cutoff current (Base open)	ICEO	VCE = -50 V, IB = 0			-0.5	μA
Emitter-base cutoff current (Collector open)	IEBO	VEB = -6 V, IC = 0			-0.2	mA
Forward current transfer ratio	hFE	VCE = -10 V, IC = -5 mA	80			-
Collector-emitter saturation voltage	VCE(sat)	IC = -10 mA, IB = -0.5 mA			-0.25	V
Input voltage	Vi(on)	VCE = -0.2 V, IC = -5 mA	-1.7			V
	Vi(off)	VCE = -5 V, IC = -100 μA			-0.5	V
Input resistance	R1		-30%	10	+30%	kΩ
Resistance ratio	R1/R2		0.17	0.21	0.25	-
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Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

Panasonic

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-0.1

-0.0001

-0.001

Output current Io (A)

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-0.1

85 °C

-0.01

Established : 2009-10-16 Revised : 2014-02-27

-1.0E-06

-0

-0.5

-1

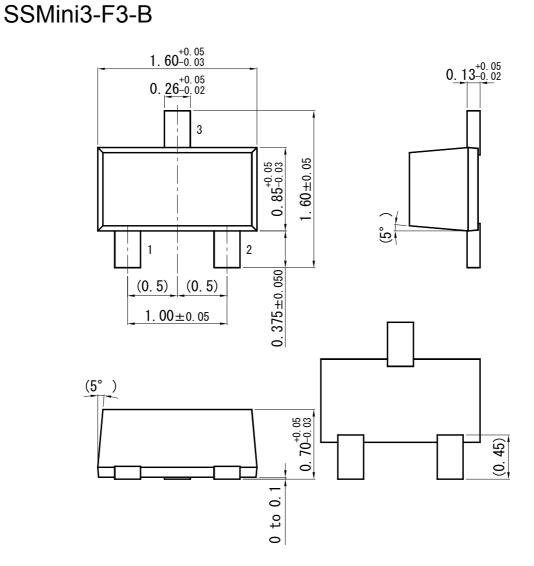
Input voltage VIN (V)

-1.5

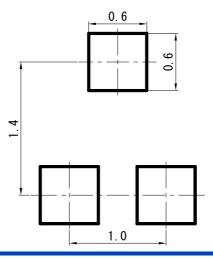
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Land Pattern (Reference) (Unit: mm)



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Unit: mm

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